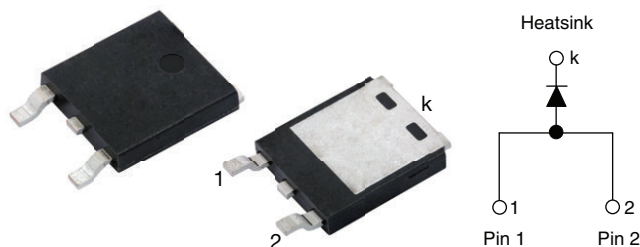


Hyperfast Rectifier, 8 A FRED Pt®

eSMP® Series



SlimDPAK (TO-252AE)

FEATURES

- Hyperfast recovery time, reduced Q_{rr} and soft recovery
- For PFC CRM / CCM operation
- Low forward voltage drop, low power losses
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
 - Automotive ordering code: base P/NHM3, meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

AUTOMOTIVE
GRADE



RoHS
COMPLIANT
HALOGEN
FREE

PRODUCT SUMMARY

Package	SlimDPAK (TO-252AE)
$I_{F(AV)}$	8 A
V_R	600 V
V_F at I_F	1.3 V
t_{rr} (typ.)	16 ns
T_J max.	175 °C
Diode variation	Single

TYPICAL APPLICATIONS

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS inverters, or as freewheeling diodes. Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

MECHANICAL DATA

Case: SlimDPAK

Molding compound meets UL 94 V-0 flammability rating

Base PN/HM3 - halogen-free, RoHS-compliant, and AEC-Q101 qualified

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Peak repetitive reverse voltage	V_{RRM}		600	V
Average rectified forward current	$I_{F(AV)}$	$T_C = 144\text{ °C}$	8	A
Non-repetitive peak surge current	I_{FSM}	$T_J = 25\text{ °C}$	90	
Operating junction and storage temperatures	T_J, T_{Stg}		-55 to +175	°C

ELECTRICAL SPECIFICATIONS ($T_J = 25\text{ °C}$ unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	V_{BR}, V_R	$I_R = 100\text{ }\mu\text{A}$	600	-	-	V
Forward voltage	V_F	$I_F = 8\text{ A}$	-	1.6	2.40	
		$I_F = 8\text{ A}, T_J = 150\text{ °C}$	-	1.3	1.7	
Reverse leakage current	I_R	$V_R = V_R$ rated	-	-	20	μA
		$T_J = 150\text{ °C}, V_R = V_R$ rated	-	-	500	
Junction capacitance	C_T	$V_R = 600\text{ V}$	-	12	-	pF



DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Reverse recovery time	t_{rr}	$I_F = 1\text{ A}$, $dI_F/dt = 50\text{ A}/\mu\text{s}$, $V_R = 30\text{ V}$	-	21	-	ns
		$I_F = 1\text{ A}$, $dI_F/dt = 100\text{ A}/\mu\text{s}$, $V_R = 30\text{ V}$	-	16	-	
		$I_F = 0.5\text{ A}$, $I_R = 1\text{ A}$, $I_{RR} = 0.25\text{ A}$	-	-	25	
		$T_J = 25\text{ }^{\circ}\text{C}$	-	25	-	
		$T_J = 125\text{ }^{\circ}\text{C}$	-	65	-	
Peak recovery current	I_{RRM}	$T_J = 25\text{ }^{\circ}\text{C}$	-	4.9	-	A
		$T_J = 125\text{ }^{\circ}\text{C}$	-	8.2	-	
Reverse recovery charge	Q_{rr}	$T_J = 25\text{ }^{\circ}\text{C}$	-	90	-	nC
		$T_J = 125\text{ }^{\circ}\text{C}$	-	260	-	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T_J, T_{Stg}		-55	-	175	$^{\circ}\text{C}$
Thermal resistance, junction to case	R_{thJC}		-	-	2.2	$^{\circ}\text{C}/\text{W}$
Marking device		Case style SlimDPAK (TO-252AE)	8EVH06			

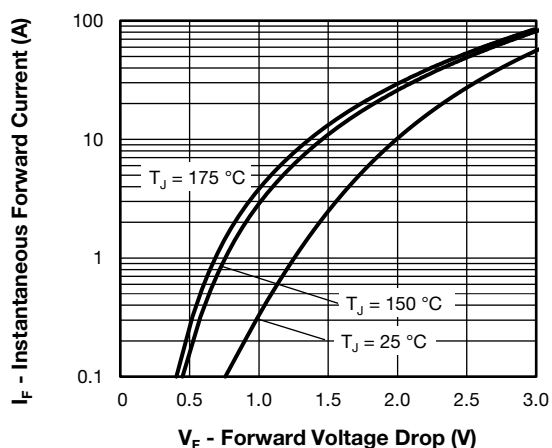


Fig. 1 - Typical Forward Voltage Drop Characteristics

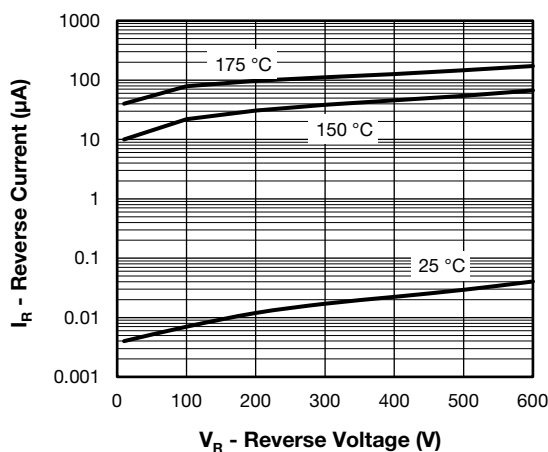


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

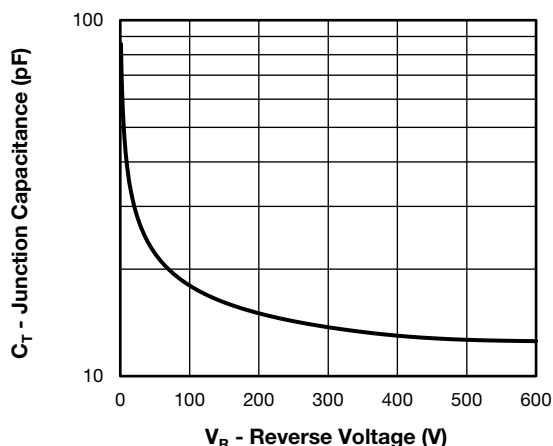


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

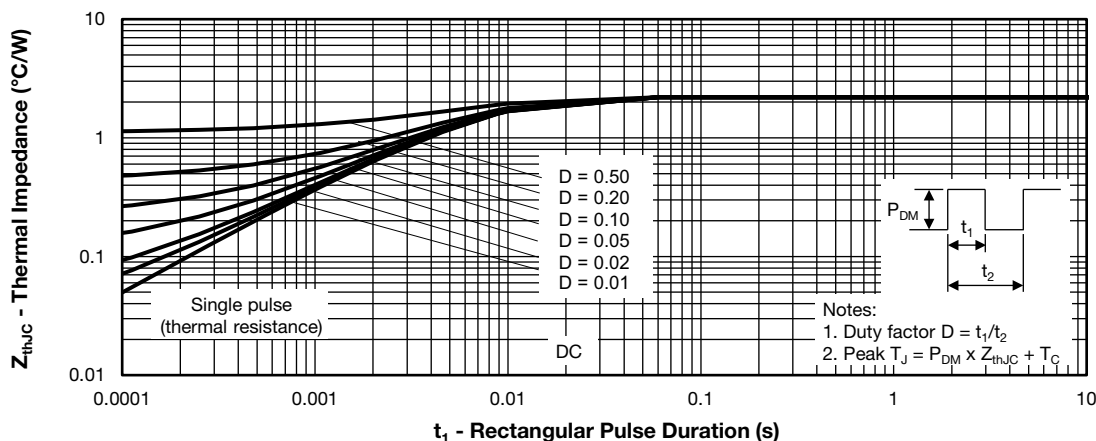
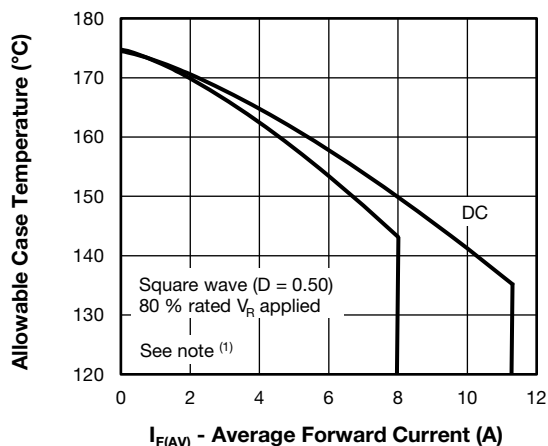

Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

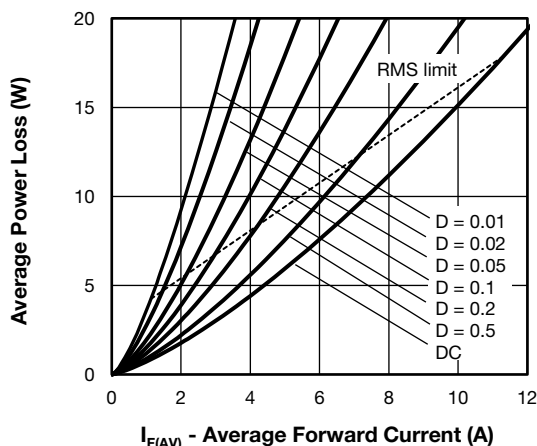


Fig. 6 - Forward Power Loss Characteristics

Note

- (1) Formula used: $T_C = T_J - (P_d + P_{dREV}) \times R_{thJC}$;
 P_d = forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6);
 P_{dREV} = inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at V_{R1} = rated V_R

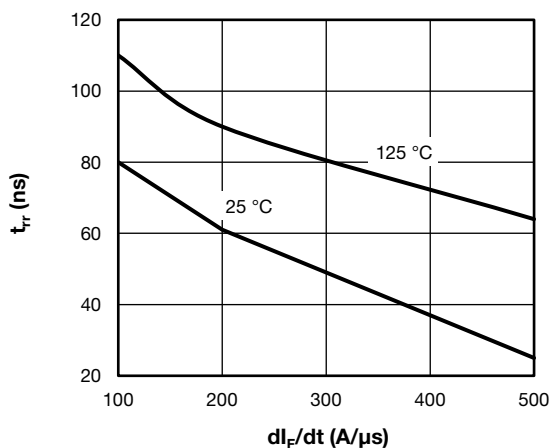
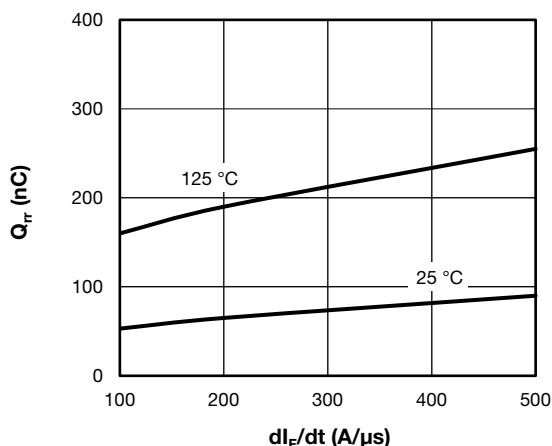
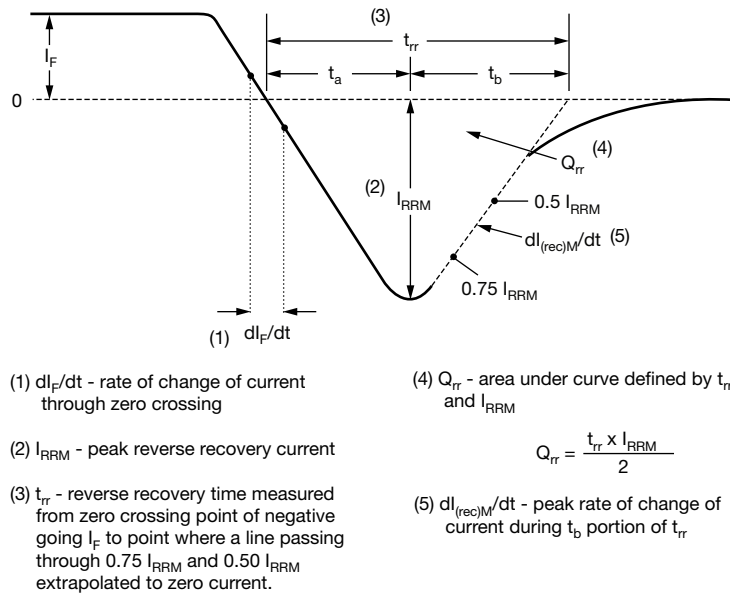

Fig. 7 - Typical Reverse Recovery Time vs. dI_F/dt

Fig. 8 - Typical Stored Charge vs. dI_F/dt


Fig. 9 - Reverse Recovery Waveform and Definitions

**ORDERING INFORMATION TABLE**

Device code	VS-	8	E	V	H	06	H	M3
	1	2	3	4	5	6	7	8
1	- Vishay Semiconductors product							
2	- Current rating (8 = 8 A)							
3	- Circuit configuration: E = single die							
4	- V = SlimDPAK							
5	- Process type: H = hyperfast recovery							
6	- Voltage code (06 = 600 V)							
7	- H = AEC-Q101 qualified							
8	- Environmental digit: M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free							

ORDERING INFORMATION (Example)

PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	PACKAGING DESCRIPTION
VS-8EVH06HM3/I	0.20	1	4500	13" diameter plastic tape and reel

LINKS TO RELATED DOCUMENTS

Dimensions	www.vishay.com/doc?96081
Part marking information	www.vishay.com/doc?96085
Packaging information	www.vishay.com/doc?88869



SlimDPAK

DIMENSIONS in inches (millimeters)



Mounting Pad Layout





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Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9